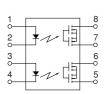


Super miniature design, SOP (2 Form A) 8-pin type. Controls load voltage 350V, 400V.

mm inch

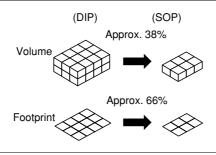


FEATURES

1. 2 channels in super miniature design

The device comes in a super-miniature SO package measuring (W) $4.4 \times (L) \ 9.37$

× (H) 2.1 mm (W) .173× (L) .369× (H) .083 inch —approx. 38% of the volume and 66% of the footprint size of DIP type PhotoMOS Relays.



2. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

GU PhotoMOS (AQW21OS)

3. Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. Low-level off state leakage current In contrast to the SSR with an off state leakage current of several milliamperes, the PhotoMOS relay features a very small off state leakage current of typ. 100 pA even with the rated load voltage of 400 V (AQW214S)

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computer
- Industrial robots
- High-speed inspection machines.

TYPES

IYPES					
Туре	Output rating*		Part No.		Packing quantity in tape
	Load voltage	Load current	Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	and reel
AC/DC	350 V	100 mA	AQW210SX	AQW210SZ	1,000 pcs.
AC/DC	400 V	80 mA	AQW214SX	AQW214SZ	1,000 pcs.

*Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suffix "X" or "Z" is not needed when ordering; Tube: 50 pcs.; Case: 1,000 pcs.)

(2) For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

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1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)
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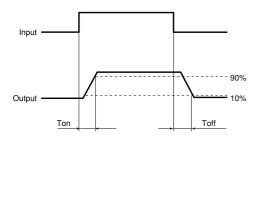
	Item	Symbol	AQW210S	AQW214S	Remarks
	LED forward current	IF	50 mA		
lana ut	LED reverse voltage	VR	5 V		
Input	Peak forward current	IFP	1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW		
	Load voltage (peak AC)	VL	350 V	400 V	
Output	Continuous load current	١L	0.1 A (0.13 A)	0.08 A (0.1 A)	(): in case of using only 1 channel Peak AC, DC
	Peak load current	Ipeak	0.3 A	0.24 A	A connection: 100 ms (1 shot), VL = DC
	Power dissipation	Pout	600 mW		
Total power dissipation		Ρτ	650 mW		
I/O isolation voltage		Viso	1,500 V AC		
Towns a water was live its	Operating	Topr	−40°C to +85°C −40°F to +185°F		Non-condensing at low temperatures
Temperature limits	Storage	Tstg	-40°C to +100°C -40°F to +212°F		

GU PhotoMOS (AQW21OS)

	Item		Symbol	AQW210S	AQW214S	Remarks
		Typical		0.9 mA		l∟ = Max.
	LED operate current	Maximum	IFon	3 mA		
Input	LED turn off current	Minimum	Foff	0.4 mA		l∟ = Max.
Input		Typical	IFott	0.8 mA		
	LED dropout voltage	Typical	VF	1.25 V (1.14 V at I⊧ = 5 mA)		I⊧ = 50 mA
	LED dropout voltage	Maximum	VF	1.5 V		
		Typical		16 Ω	30 Ω	I⊧ = 5 mA I∟ = Max. Within 1 s on time
Output	On resistance	Maximum	Ron	35 Ω	50 Ω	
	Off state leakage current	Maximum	lleak	1 μΑ		I⊧ = 0 mA V∟ = Max.
Transfer characteristics	Turn on time*	Typical	Ton -	0.23 ms	0.21 ms	I⊧ = 5 mA
	Turn on time	Maximum	Ion	0.5 ms		I∟ = Max.
	Turn off time*	Typical	T _{off}	0.04 ms		I⊧ = 5 mA I∟ = Max.
		Maximum	loff	0.2 ms		
		Typical	0	0.8 pF		f = 1 MHz Vв = 0 V
	I/O capacitance	Maximum	Ciso	1.5 pF		
	Initial I/O isolation resistance	Minimum	Riso	1,000 MΩ		500 V DC

Note: Recommendable LED forward current $I_F = 5$ mA.

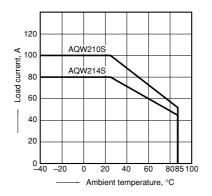
*Turn on/ Turn off time



REFERENCE DATA

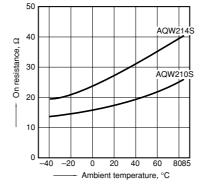
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



2. On resistance vs. ambient temperature characteristics

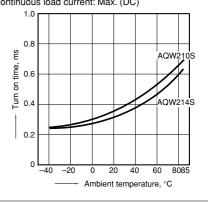
Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;

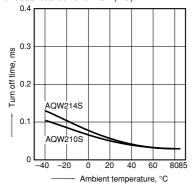
Load voltage: Max. (DC); Continuous load current: Max. (DC)



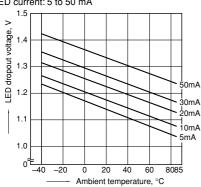
GU PhotoMOS (AQW21OS)

4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

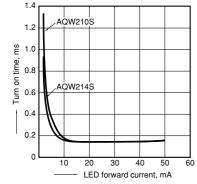


7. LED dropout voltage vs. ambient temperature characteristics Sample: All types; LED current: 5 to 50 mA



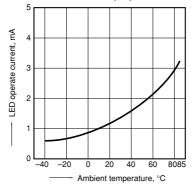
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



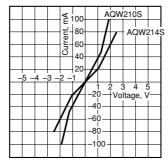
5. LED operate current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



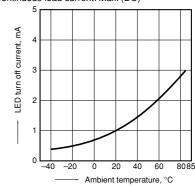
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



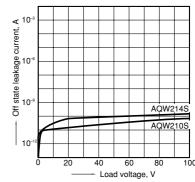
6. LED turn off current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



9. Off state leakage current vs. load voltage characteristics

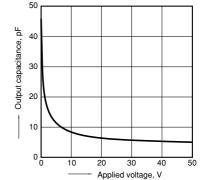
Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz;

Ambient temperature: 25°C 77°F



11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$

